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Universal electric current of interacting resonant-level models with asymmetric interactions: An extension of the Landauer formula

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Abstract

We study the electron transport in open quantum-dot systems described by the interacting resonant-level models with Coulomb interactions. We consider the situation in which the quantum dot is connected to the left and right leads asymmetrically. We exactly construct many-electron scattering eigenstates for the two-lead system, where two-body bound states appear as a consequence of one-body resonances and the Coulomb interactions. By using an extension of the Landauer formula, we calculate the average electric current for the system under bias voltages in the first order of the interaction parameters. Through a renormalization-group technique, we arrive at the universal electric current, where we observe the suppression of the electric current for large bias voltages, i.e., negative differential conductance. We find that the suppressed electric current is restored by the asymmetry of the system parameters.

I. INTRODUCTION

In the last two decades, much progress has been made in the experimental studies of the electron transport in nanoscale devices[1–4]. In the systems smaller than the coherent length, quantum effects are observed in the electron transport[5,6]. In order to analyze it beyond the linear-response regime theoretically, we need to treat nonequilibrium steady states realized in *open* quantum systems. The Landauer formula[7,8] enables the calculation of the electric current flowing across nanoscale samples in noninteracting cases, which indicates that the nonequilibrium steady states are scattering states in the open quantum systems. Indeed, the transport properties such as the electrical conductance and the electric-current noise are determined by the scattering matrix[9–11]. To investigate interacting cases, the Keldysh formalism of the nonequilibrium Green's function has been developed[12–16]. It has provided a standard tool for the study of the Kondo effect measured as a conductance peak in semiconductor quantum dots (QDs)[17,18]. On the other hand, we have proposed an extension of the Landauer formula to interacting cases[19,20], and have shown that the scattering states are essential in the interacting cases as well.

The interacting resonant-level model (IRLM) is one of the standard testbeds for such studies of the open QD systems with interactions. The original IRLM, which consists of a single impurity coupled to a conduction band, was introduced for studying the Kondo problem in equilibrium systems[21]. Recently, the IRLM with *two* external leads has been employed as a minimal model of open QD systems with Coulomb interactions; it plays an important role in verifying the theoretical approaches such as the nonequilibrium Bethe-ansatz approach[22], the perturbation theory with the numerical renormalization group[23], a new method called impurity conditions[24] and the time-dependent density-matrix renormalization-group method[25].

A remarkable feature of the two-lead IRLM is the appearance of *negative differential conductance*, that is, the suppression of the electric current due to the Coulomb interaction for large bias voltages. Clearly, this is a phenomenon out of the linear-response regime. To see the feature and to compare the results obtained by different approaches, the *universal electric current* characterized by a single scaling parameter T_{K} is useful[24,26,27]. Indeed, it is found that, for large bias voltages V, the universal electric current shows a power-law decay $\langle I \rangle \propto (V/T_{\mathrm{K}})^{-U/\pi}$ with the parameter U of the Coulomb interaction[24,25].

In the previous papers[19,20], we proposed an extension of the Landauer formula with many-electron scattering eigenstates. We considered the two-lead IRLM with linearized dispersion relations and gave *exact* many-electron scattering eigenstates in explicit forms. This is in contrast to the previous studies[28–30] of the scattering problems for other QD systems, which include integrals or matrix inversions. The explicit N-electron scattering eigenstates enabled us to calculate the quantum-mechanical expectation value of the electric current, which we called the N-electron current. By taking the electron-reservoir limit $N \to \infty$ of the N-electron current, we obtained the average electric current for the system under finite bias voltages. It is clear that the way of realizing the nonequilibrium steady states in our extension of the Landauer formula is different from the Keldysh formalism[12–16]. By employing a renormalization-group technique with the Callan-Symanzik equation[24,27], we arrived at the universal electric current in the first order of the interaction parameter U. We found that the negative differential conductance of the universal electric current is characterized by the same scaling parameter T_{K} as that obtained by other approaches[24,27,31]. We remark that the apparent inconsistency in Ref. 19 pointed out in Ref. 32 is removed in the level of the universal electric current[33].

In the present paper, we study the two-lead IRLM in which the QD is connected to the two external leads *asymmetrically.* The effect of the asymmetry of the QD systems is observed in experiments. For example, in semiconductor QDs[3,4], the asymmetry of the lead-dot couplings causes breaking of the unitary limit of the Kondo effect, which is theoretically understood in the linear-response regime[17,18]. In the present study, we investigate the effect of the asymmetry on electron transport out of the linear-response regime. One of the theoretical difficulties of the asymmetric cases is that the even-odd transformation, which maps the two-lead IRLM to two single-lead systems[19,20,22], does not work. The application of the Bethe-ansatz approach[22] has been restricted to the cases in which the even-odd transformation works. The construction of exact many-electron scattering eigenstates for such pure two-lead systems is established for the first time in this paper.

Through the extension of the Landauer formula and a renormalization-group technique, we obtain the universal electric current for the asymmetric cases in the first order of the Coulomb-interaction parameters U_1 and U_2. The universal electric current is characterized by the two renormalized parameters T_1 and T_2. The sum $T_{\mathrm{K}} = T_1 + T_2$ provides a scaling parameter for the bias voltage V, which is similar to the symmetric cases. Our universal electric current has the same functional form as that obtained by the renormalization-group approach[31,32], although there is a difference in our calculation of the renormalized parameters T_1 and T_2. As we will point at the end of Section IV, this leads to a critical difference in the predicted behavior of the universal electric current. The suppressed electric current due to the Coulomb interaction is restored by the asymmetry of the system parameters. To clarify the relation between the asymmetry of the system parameters and the restoration of the suppressed electric current, we introduce the asymmetry parameter $\delta = (U_1 - U_2)(T_1 - T_2)/(2T_\mathrm{K})$ taking the value in the range $0 \leq \delta < \bar{U}$ with the average interaction $\bar{U} = (U_1 + U_2)/2$. In fact, in the first order of U_1 and U_2, the power-law decay of the universal electric current is given by $\langle I \rangle \propto (V/T_\mathrm{K})^{-(\bar{U}-\delta)/\pi}$, which indicates that the restoration of the suppressed electric current occurs with both asymmetric Coulomb interactions and asymmetric lead-dot couplings. The restoration was reported to happen even for symmetric lead-dot couplings in Refs. 31 and 32, but we presume that this was due to higher orders of the interaction U_ℓ in the renormalized parameters T_1 and T_2.

The exact many-electron scattering eigenstates tell us much about the transport properties of interacting electrons in the open QD systems. We notice that the scattering processes in which the set of wave numbers of incident plane waves is not conserved are essential in interacting cases. The explicit form of the scattering eigenstates indicates that, due to the Coulomb interactions, the incident plane-wave states are partially scattered to *many-body bound states* that decay exponentially as the electrons separate from each other. Indeed, the two-body bound states appear in the two-lead IRLM; each term of the N-electron scattering states is characterized by the configuration of the two-body bound states. We can understand the origin of the negative differential conductance in the two-lead IRLM in terms of the formation of two-body bound states. Such many-body bound states are also found in other open QD systems[34,35].

The present paper is organized as follows. In Sec. II A, we introduce the two-lead IRLM with asymmetric interactions. In Sec. II B, the extension of the Landauer formula[19,20] is described in a general setting. In Sec. III, we present the construction of the exact one- and two-electron scattering eigenstates whose incident states are free-electronic plane waves in the leads. We also give the N-electron scattering eigenstates in the first order of the Coulomb-interaction parameters. In Sec. IV, through the extension of the Landauer formula, we calculate the average electric current for the system under finite bias voltages. We obtain the universal electric current by dealing with the divergences in the average electric current with the Callan-Symanzik equation. As a result, we observe the negative differential conductance and the restoration of the suppressed electric current. Section V is devoted to concluding remarks.

II. MODELS AND FORMULATION

A. Interacting resonant-level models

We consider the open QD system described by the IRLM of spinless electrons. It consists of a QD with a single energy level and two external leads of noninteracting electrons. The arrangement of the QD and the two leads is illustrated in Fig. 1. We assume the situation in which the QD is connected to the two leads asymmetrically.

The Hamiltonian is given by

$$\begin{aligned} H = &\sum_{\ell=1,2} \int_{-\frac{L}{2}}^{\frac{L}{2}} dx\, c_\ell^\dagger(x) \frac{1}{\mathrm{i}} \frac{d}{dx} c_\ell(x) + \sum_{\ell=1,2} \left(t_\ell c_\ell^\dagger(0) d + t_\ell^* d^\dagger c_\ell(0) \right) + \epsilon_{\mathrm{d}} d^\dagger d \\ &+ \sum_{\ell=1,2} U_\ell c_\ell^\dagger(0) c_\ell(0) d^\dagger d. \end{aligned} \tag{1}$$

Here $c_\ell^\dagger(x)$ and $c_\ell(x)$ are the creation- and the annihilation-operators of an electron in the lead ℓ, while $d^\dagger$ and d are those on the QD. The first term corresponds to the kinetic energy of electrons in the leads, where L stands for the length of the two leads to be eventually taken to infinity. The second term expresses the tunneling between the leads and the QD, where the parameter $t_\ell (\in \mathbb{C})$ is the transfer integral. We assume a single energy level $\epsilon_{\mathrm{d}} (\in \mathbb{R})$ on the QD, which corresponds to the third term. The fourth term describes the Coulomb interaction between the two electrons at the origin $x = 0$ of the lead ℓ and on the QD. The parameter $U_\ell (> 0)$ is the strength of the Coulomb repulsion.

We focus on the electrons with positive velocities in the vicinity of the Fermi energy ϵ_{F} of each lead and linearize the local dispersion relation to be $\epsilon(k) = v_{\mathrm{F}}(k - k_{\mathrm{F}}) + \epsilon_{\mathrm{F}}$ under the assumption that the other parameters $|t_\ell|$, $|\epsilon_{\mathrm{d}}|$ and U_ℓ are small compared with the Fermi energy ϵ_{F}[21]. For simplicity, we have set $v_{\mathrm{F}} = 1$, $k_{\mathrm{F}} = 0$ and $\epsilon_{\mathrm{F}} = 0$ in Eq. (1). Then, as is indicated in Fig. 1, an electron coming from the part $x < 0$ of the lead 1 is scattered at the QD to the parts $x > 0$ of the two leads.

In constructing the scattering eigenstates, we treat the system as an open system in the limit $L \to \infty$ of the two leads. In the sprit of the original Landauer formula[7,8], we

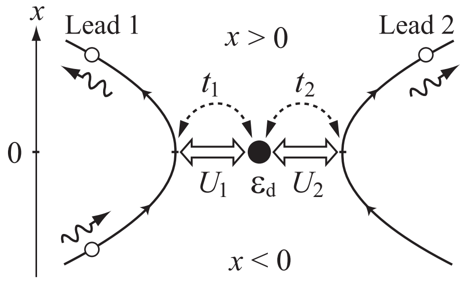

FIG. 1: The two-lead interacting resonant-level model. Electrons flow only upward due to the linearized dispersion relations of the leads.

suppose that the infinite two leads can substitute for electron reservoirs that are in the Fermi degenerate states of noninteracting electrons. We assume that the electrons emitted from the electron reservoir into the lead ℓ follow the Fermi distribution function $f_{\mu_\ell,\beta_\ell}(E) = 1/(1+\mathrm{e}^{\beta_\ell(E-\mu_\ell)})$ with the chemical potential μ_ℓ and the inverse temperature β_ℓ. We are interested in the nonequilibrium steady state realized between the large two electron reservoirs in the cases $\mu_1 \neq \mu_2$ of different chemical potentials.

We adopt a standard definition of the electric-current operator as

$$I = \alpha I_1 - (1-\alpha) I_2, \quad I_\ell = \imath\big(t_\ell c_\ell^\dagger(0) d - t_\ell^* d^\dagger c_\ell(0)\big). \quad (\ell = 1, 2) \tag{2}$$

For an arbitrary eigenstate $|\psi\rangle$ of the Hamiltonian H, the expectation value $\langle\psi|I|\psi\rangle$ does not depend on the parameter α since the relation $\langle\psi|I_1|\psi\rangle = -\langle\psi|I_2|\psi\rangle$ holds. In what follows, we choose the parameter $\alpha = |t_2|^2/t^2$ with $t = \sqrt{|t_1|^2 + |t_2|^2}$ for the convenience of calculations.

B. Extension of the Landauer formula

Our purpose is to study the average electric current flowing across the QD of the two-lead IRLM beyond the linear-response regime. The extension of the Landauer formula, which was proposed in Refs. 19 and 20, consists of the following three steps:

(i) Construction of many-electron scattering eigenstates whose incident states are free-electronic plane waves in the leads;

(ii) Calculation of the quantum-mechanical expectation value of the electric current with the many-electron scattering eigenstates;

(iii) Calculation of the statistical-mechanical average of the electric current by assuming the equilibration of electrons in each electron reservoir.

The many-electron scattering eigenstates constructed in the step (i) are characterized by the wave numbers of the incident plane waves. We note that they are essentially different from the Bethe-ansatz eigenstates[21,22], whose incident states are not free electronic but include the effect of interactions. The Bethe-ansatz result in Ref. 22 did not agree with results of the previous works[24,25,27] while our results agree with them. For the wave numbers $\{k_1, \ldots, k_{N_1}\}$ of the N_1-electron incident plane wave coming in through the lead 1 and $\{h_1, \ldots, h_{N_2}\}$ of the N_2-electron incident plane wave coming in through the lead 2, we express the N-electron scattering eigenstates by $|k, h\rangle = |k_1, \ldots, k_{N_1}, h_1, \ldots, h_{N_2}\rangle$ with $N = N_1 + N_2$. In the step (ii), we calculate the expectation value $\langle k, h|I|k, h\rangle / \langle k, h|k, h\rangle$ of the electric-current operator I, which we call the N-electron current. This calculation is practically carried out by using the explicit N-electron scattering eigenstates. In the step (iii), we take the limit $N_\ell, L \to \infty$ of the N-electron current by assuming that the wave numbers k_i and h_i of incident plane waves follow the Fermi distribution of each electron reservoir. We call the limit an electron-reservoir limit. Clearly, the reservoir limit corresponds to taking the statistical-mechanical average of the electric current for all the incident states that follow the Fermi distributions. In general, the electrons scattered at the QD are in many-body states including the effect of interactions. We assume that such many-body states are completely equilibrated to the Fermi degenerate state of free electrons in each election reservoir before being re-emitted towards the QD, which is the main assumption of the extension of the Landauer formula. We shall see for the two-lead IRLM that, since the N-dependence of the N-electron current appears only in the upper bounds of the sums on wave numbers $\{k_i\}$ and $\{h_i\}$, we can take the reservoir limit by replacing the sums with the integrals on k and h with the Fermi-distribution functions $f_{\mu_1,\beta}(k)$ and $f_{\mu_2,\beta}(h)$.

The way of realizing the nonequilibrium steady states in the extension of the Landauer formula is different from that in the Keldysh formalism[12–16,27]. In our extension of the Landauer formula, we first construct the N-electron scattering eigenstates for finite N without the information of the equilibrium states in the electron reservoirs. After the calculation of the N-electron current, we take the reservoir limit to consider the nonequilibrium steady state. In the Keldysh formalism, on the other hand, the Green's functions or the density operator describing the nonequilibrium steady states are obtained by adiabatically turning on the perturbative terms for the initial nonperturbative steady states of infinite number of electrons.

Our approach is also independent of Hershfield's bias-operator approach, which constructs the density operator of the nonequilibrium steady states directly from one-electron field operators in the framework of the quantum field theory[36–38]. We remark that the construction of the density operator through the bias-operator approach has not been established analytically in interacting cases[37,38] except for the Toulouse limit of the Kondo model[39,40].

III. MANY-ELECTRON SCATTERING EIGENSTATES

A. One-electron cases

The linearization of the local dispersion relations of the leads enables us to construct exact scattering eigenstates. First, we consider the one-electron cases. The one-electron scattering eigenstates are given in the form

$$|E\rangle = \Big(\int dx \sum_{m=1,2} g_m(x) c^\dagger_m(x) + e d^\dagger \Big) |0\rangle, \tag{3}$$

where $|0\rangle$ is the vacuum state satisfying $c_\ell(x)|0\rangle = d|0\rangle = 0$. The eigenfunctions $g_m(x)$ and e are determined by the coupled Schrödinger equations:

$$\begin{aligned} &\Big(\frac{1}{\imath}\frac{d}{dx} - E\Big) g_m(x) + t_m e \delta(x) = 0, \quad (m = 1, 2) \\ &(\epsilon_\mathrm{d} - E)e + \sum_{m=1,2} t^*_m g_m(0) = 0. \end{aligned} \tag{4}$$

It is readily found that the eigenfunction $g_m(x)$ is discontinuous at $x = 0$ and the matching condition at $x = 0$ is obtained by integrating the first equation in Eqs. (4) around $x = 0$ as

$$g_m(0+) - g_m(0-) + \imath t_m e = 0. \tag{5}$$

Since the value $g_m(0)$ is not determined by the Schrödinger equations, we assume $g_m(0) = (g_m(0+) + g_m(0-))/2$ from physical intuition.

To employ the Landauer formula, we need the scattering eigenstates whose incident states are a plane wave in the lead 1 or the lead 2. For the incident plane wave with the wave number k in the lead ℓ, we consider the solution $g^{(\ell)}_{m,k}(x)$ and $e^{(\ell)}_k$ of the Schrödinger equations (4) satisfying

$$g_{m,k}^{(\ell)}(x) = \frac{1}{\sqrt{2\pi}}\delta_{m\ell}\mathrm{e}^{\imath kx} \quad \text{for } x < 0, \tag{6}$$

where $\delta_{m\ell}$ is the Kronecker delta. We refer to Eq. (6) as scattering boundary conditions. The solution with energy eigenvalue $E = k$ is given by

$$\begin{aligned} g_{m,k}^{(\ell)}(x) &= \frac{1}{\sqrt{2\pi}}\big(\delta_{m\ell} - \imath t_m\sqrt{2\pi}e_k^{(\ell)}\theta(x)\big)\mathrm{e}^{\imath kx}, \\ e_k^{(\ell)} &= \frac{1}{\sqrt{2\pi}}\frac{t_\ell^*}{k - \epsilon_\mathrm{d} + \imath\Gamma}, \end{aligned} \tag{7}$$

where $\theta(x)$ is the step function and $\Gamma = (|t_1|^2 + |t_2|^2)/2$ is the level width of the QD. By inserting them into Eq. (3), we obtain the scattering eigenstate $|k;\ell\rangle$ whose incident state is a plane wave with wave number k in the lead ℓ.

The one-electron scattering eigenstates $|k;\ell\rangle$ are normalized on the δ-function as $\langle k;\ell|k';\ell'\rangle = \delta_{\ell\ell'}\delta(k-k')$ in the limit $L \to \infty$. In the calculation of quantum-mechanical expectation values of physical quantities with the scattering eigenstates $|k;\ell\rangle$, we need to restore the length L of the leads in order to regularize the square norm as $\langle k;\ell|k;\ell\rangle = L/(2\pi)$.

B. Two-electron cases

We next consider the two-electron cases as the simplest example of the interacting cases. The form of the two-electron scattering eigenstates is given by

$$|E\rangle = \Big(\sum_{l,m=1,2}\int_{x_1<x_2} dx_1dx_2\, g_{lm}(x_1,x_2)c_l^\dagger(x_1)c_m^\dagger(x_2) + \sum_{l=1,2}\int dx\, e_l(x)c_l^\dagger(x)d^\dagger\Big)|0\rangle. \tag{8}$$

Here we impose the antisymmetric relation $g_{lm}(x_1,x_2) = -g_{ml}(x_2,x_1)$. The eigenvalue problem $H|E\rangle = E|E\rangle$ leads to the coupled Schrödinger equations:

$$\Big(\frac{1}{\imath}\Big(\frac{\partial}{\partial x_1} + \frac{\partial}{\partial x_2}\Big) - E\Big)g_{lm}(x_1,x_2) + t_m e_l(x_1)\delta(x_2) - t_l\delta(x_1)e_m(x_2) = 0, \tag{9a}$$

$$\Big(\frac{1}{\imath}\frac{d}{dx} + \epsilon_\mathrm{d} + U_l\delta(x) - E\Big)e_l(x) + \sum_{m=1,2} t_m^* g_{lm}(x,0) = 0. \tag{9b}$$

In the previous works[19,20] for the symmetric case $U_1 = U_2$, we employed the even-odd transformation that maps the two-lead IRLM to two single-lead systems. However, since the transformation does not work for the asymmetric cases $U_1 \neq U_2$, we deal with the two-lead IRLM directly.

We present a construction of the exact two-electron scattering eigenstates, which is an extension of the previous one[19,20,41]. First, we derive three important relations from the Schrödinger equations (9a) and (9b). The eigenfunction $g_{lm}(x_1, x_2)$ is discontinuous at $x_1 = 0$ and $x_2 = 0$, while $e_l(x)$ is discontinuous at $x = 0$. The matching conditions at the discontinuous points are given by

$$g_{lm}(x, 0+) - g_{lm}(x, 0-) + \imath t_m e_l(x) = 0, \tag{10a}$$

$$e_l(0+) - e_l(0-) + \imath U_l e_l(0) = 0, \tag{10b}$$

which are obtained by integrating the Schrödinger equations (9a) and (9b) around the discontinuous points. Since the values of the eigenfunctions at the discontinuous points are not determined by the Schrödinger equations, we assume

$$g_{lm}(x, 0) = \frac{1}{2}\big(g_{lm}(x, 0+) + g_{lm}(x, 0-)\big), \tag{11a}$$

$$e_l(0) = \frac{1}{2}\big(e_l(0+) + e_l(0-)\big) \tag{11b}$$

in a way similar to the one-electron cases. By applying Eqs. (10a) and (11a) to Eq. (9b) for $x \neq 0$, we have

$$\Big(\frac{1}{\imath}\frac{d}{dx} + \epsilon_{\mathrm{d}} - \imath\Gamma - E\Big) e_l(x) = -\sum_m t_m^* g_{lm}(x, 0-). \tag{12}$$

Given functions $g_{lm}(x, 0-)$, $(m = 1, 2)$, we obtain the general solution for $e_l(x)$ as

$$e_l(x) = C_l \mathrm{e}^{\imath(E-\epsilon_{\mathrm{d}}+\imath\Gamma)x} - \imath \sum_m t_m^* \int_{x_0}^{x} dz\, \mathrm{e}^{\imath(E-\epsilon_{\mathrm{d}}+\imath\Gamma)(x-z)} g_{lm}(z, 0-), \tag{13}$$

where C_l is the integration constant and x_0 is chosen as $x_0 = -\infty$ if $x < 0$ and $x_0 = 0$ otherwise. On the other hand, by applying Eq. (11b) to Eq. (10b), we have the matching condition

$$\Big(1 + \frac{\imath}{2} U_l\Big) e_l(0+) = \Big(1 - \frac{\imath}{2} U_l\Big) e_l(0-). \tag{14}$$

The equations (10a), (13) and (14) are the relations that we need.

Next, we demonstrate how to construct the two-electron scattering eigenstates by the repeated use of the three equations (10a), (13) and (14). Let us consider the situation in which one electron with wave number k_1 is coming in through the lead ℓ_1 and another with

(ℓ_1,ℓ_2)	$A_{11,(12)}$	$A_{11,(21)}$	$A_{12,(12)}$	$A_{12,(21)}$	$A_{22,(12)}$	$A_{22,(21)}$
$(1,1)$	1	-1	0	0	0	0
$(1,2)$	0	0	1	0	0	0
$(2,2)$	0	0	0	0	1	-1

TABLE I: The coefficients $A_{\ell m,P}$ of the incident plane-wave states for $(\ell_1,\ell_2)=(1,1),(1,2)$ and $(2,2)$.

k_2 is coming in through the lead ℓ_2. We construct the eigenfunctions with energy eigenvalue $E=k_1+k_2$ that satisfy the scattering boundary conditions

$$g_{lm}(x_1,x_2)=\frac{1}{2\pi}\sum_P A_{lm,P}\mathrm{e}^{\imath(k_{P_1}x_1+k_{P_2}x_2)} \tag{15}$$

for $x_1,x_2<0$. Here $P=(P_1,P_2)$ is a permutation of $(1,2)$ and the coefficients $A_{lm,P}$ are given by $A_{lm,P}=\mathrm{sgn}(P)\delta_{l\ell_{P_1}}\delta_{m\ell_{P_2}}$ with the signature $\mathrm{sgn}(P)$ of the permutation P. The coefficients $A_{lm,P}$ are explicitly listed on Table I. Beginning from the incident state $g_{\ell m}(x_1,x_2)$ in the region $x_1<x_2<0$, we connect it to the other regions through Eqs. (10a), (13) and (14). By inserting $g_{lm}(x,0-)$ into Eq. (13), we have

$$e_l(x)=\frac{1}{\sqrt{2\pi}}\sum_{P,m}A_{lm,P}e^{(m)}_{k_{P_2}}\mathrm{e}^{\imath k_{P_1}x} \tag{16}$$

for $x<0$. Here we have set $x_0=-\infty$ and have taken $C_l=0$ to avoid the divergence as $x\to-\infty$. The function $g_{lm}(x,0-)$ is connected to $g_{lm}(x,0+)$ by Eq. (10a) with Eq. (16) as

$$g_{lm}(x,0+)=\frac{1}{2\pi}\sum_{P,n}A_{ln,P}\mathrm{e}^{\imath k_{P_1}x}(\delta_{mn}-\imath t_m\sqrt{2\pi}e^{(n)}_{k_{P_2}}), \tag{17}$$

which leads to

$$g_{lm}(x_1,x_2)=\frac{1}{\sqrt{2\pi}}\sum_{P,n}A_{ln,P}\mathrm{e}^{\imath k_{P_1}x_1}g^{(n)}_{m,k_{P_2}}(x_2) \tag{18}$$

for $x_1<0<x_2$. Recall that $g^{(n)}_{m,k}(x)$ is the one-electron scattering eigenfunction in Eqs. (7). Again, by inserting $g_{lm}(x,0-)$ into Eq. (13), we have

$$e_l(x)=C'_l\mathrm{e}^{\imath(E-\epsilon_\mathrm{d}+\imath\Gamma)x}-\sum_{P,m,n}A_{mn,P}g^{(n)}_{l,k_{P_2}}(x)e^{(m)}_{k_{P_1}} \tag{19}$$

for $x > 0$. Here we keep the first term with the integration constant C'_l since the term is not divergent as $x \to \infty$. By inserting $g_{lm}(0-, x)$ and $e_l(x)$, $(x > 0)$ into Eq. (10a) with the antisymmetric relation $g_{lm}(x_1, x_2) = -g_{ml}(x_2, x_1)$, we have

$$g_{lm}(x_1, x_2) = \sum_{P,r,n} A_{rn,P}\, g^{(r)}_{l,k_{P_1}}(x_1) g^{(n)}_{m,k_{P_2}}(x_2) + \imath t_l C'_m \mathrm{e}^{\imath((\epsilon_{\mathrm{d}} - \imath\Gamma)x_1 + (E - \epsilon_{\mathrm{d}} + \imath\Gamma)x_2)} \tag{20}$$

for $0 < x_1 < x_2$. Finally, by inserting Eqs. (16) and (19) into Eq. (14), we determine the integration constant C'_l as

$$C'_l = \frac{1}{\sqrt{2\pi}} \imath u_l \big(\delta_{l\ell_2} e^{(\ell_1)}_{k_1} - \delta_{l\ell_1} e^{(\ell_2)}_{k_2} \big) \tag{21}$$

with $u_l = 2U_l/(2 + \imath U_l)$. Thus the two-electron scattering eigenfunctions satisfying the scattering boundary conditions (15) are obtained as follows:

$$\begin{aligned} g^{(\ell_1\ell_2)}_{lm,k_1k_2}(x_1, x_2) &= g^{(\ell_1)}_{l,k_1}(x_1) g^{(\ell_2)}_{m,k_2}(x_2) - g^{(\ell_2)}_{l,k_2}(x_1) g^{(\ell_1)}_{m,k_1}(x_2) \\ &\quad + t_l u_m Z^{(\ell_1\ell_2)}_{m,k_1k_2}(x_{12}) \mathrm{e}^{\imath E x_2} \theta(x_{21}) \theta(x_1) - t_m u_l Z^{(\ell_1\ell_2)}_{l,k_1k_2}(x_{21}) \mathrm{e}^{\imath E x_1} \theta(x_{12}) \theta(x_2), \\ e^{(\ell_1\ell_2)}_{l,k_1k_2}(x) &= g^{(\ell_1)}_{l,k_1}(x) e^{(\ell_2)}_{k_2} - g^{(\ell_2)}_{l,k_2}(x) e^{(\ell_1)}_{k_1} - \imath u_l Z^{(\ell_1\ell_2)}_{l,k_1k_2}(-x) \mathrm{e}^{\imath E x} \theta(x), \end{aligned} \tag{22}$$

where $x_{ij} = x_i - x_j$ and

$$Z^{(\ell_1\ell_2)}_{m,k_1k_2}(x) = \frac{1}{\sqrt{2\pi}} (\delta_{m\ell_1} e^{(\ell_2)}_{k_2} - \delta_{m\ell_2} e^{(\ell_1)}_{k_1}) \mathrm{e}^{\imath(\epsilon_{\mathrm{d}} - \imath\Gamma)x}. \tag{23}$$

Here, on the left-hand sides of Eqs. (22) and (23), we write the wave numbers k_1 and k_2 and the superscripts ℓ_1 and ℓ_2 of the leads explicitly.

Each term of the eigenfunctions in Eqs. (22) is interpreted as follows. The first two terms correspond to the two-electron scattering eigenfunctions of the noninteracting cases, which are given by the Slater determinant of the one-electron scattering eigenfunctions in Eq. (7). The effects of the interactions appear in the terms with the function $Z^{(\ell_1\ell_2)}_{m,k_1k_2}(x)$. They are interpreted as *two-body bound states* since they decay exponentially as the two electrons separate from each other. For example, the third and the fourth terms in the eigenfunction $g^{(\ell_1\ell_2)}_{lm,k_1k_2}(x_1, x_2)$ in Eq. (22) are rewritten as

$$\begin{aligned} & t_l u_m Z^{(\ell_1\ell_2)}_{m,k_1k_2}(x_{12}) \mathrm{e}^{\imath E x_2} \theta(x_{21}) \theta(x_1) - t_m u_l Z^{(\ell_1\ell_2)}_{l,k_1k_2}(x_{21}) \mathrm{e}^{\imath E x_1} \theta(x_{12}) \theta(x_2) \\ &= \big(t_l u_m Z^{(\ell_1\ell_2)}_{m,k_1k_2}(0) \theta(x_{21}) - t_m u_l Z^{(\ell_1\ell_2)}_{l,k_1k_2}(0) \theta(x_{12}) \big) \mathrm{e}^{(\imath(\frac{E}{2} - \epsilon_{\mathrm{d}}) - \Gamma)|x_1 - x_2| + \imath E \frac{x_1 + x_2}{2}} \theta(x_1) \theta(x_2). \end{aligned} \tag{24}$$

The binding length of the two-body bound states is given by $1/\Gamma$ where Γ is the level width of the QD. It should be emphasized that the two-body bound states are characteristic to

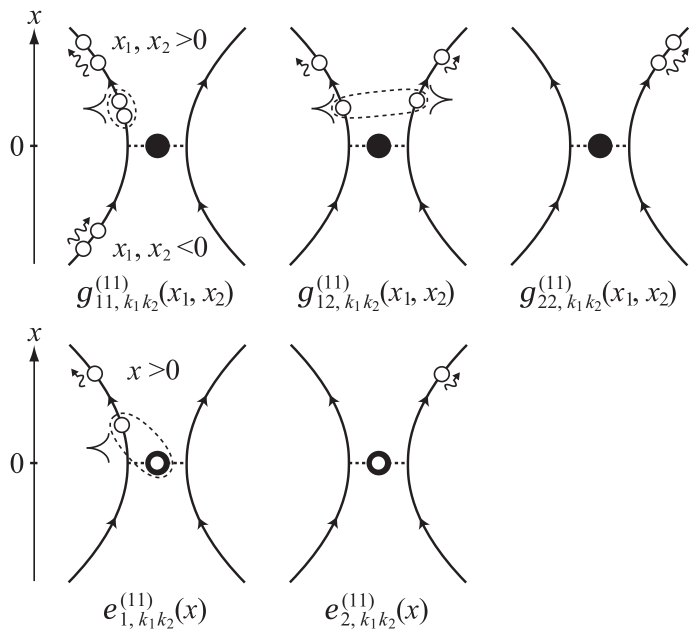
x
$x_1, x_2 > 0$
0
$x_1, x_2 < 0$
$g^{(11)}_{11,k_1k_2}(x_1,x_2)$
$g^{(11)}_{12,k_1k_2}(x_1,x_2)$
$g^{(11)}_{22,k_1k_2}(x_1,x_2)$
x
$x > 0$
0
$e^{(11)}_{1,k_1k_2}(x)$
$e^{(11)}_{2,k_1k_2}(x)$

FIG. 2: The two-electron scattering eigenfunctions for the incident two electrons coming in through the lead 1. The dotted circles surrounding the two electrons indicate the two-body bound states, which appear only when at least one of the electrons is reflected.

open systems and do not appear under periodic boundary conditions. We also find that the two-body bound states are associated with the electron that is reflected at the QD. For example, if the incident two electrons come in through the lead 1 ($\ell_1 = \ell_2 = 1$), the two-body bound states appear only in the eigenfunctions $g^{(11)}_{11,k_1k_2}(x_1, x_2)$, $g^{(11)}_{12,k_1k_2}(x_1, x_2)$ and $e^{(11)}_{1,k_1k_2}(x)$ since $Z^{(11)}_{2,k_1k_2}(x) = 0$ as is depicted in Fig. 2.

It is instructive to inspect the set of wave numbers characterizing each term of the eigenfunctions in Eqs. (22). As is found from the terms of the two-body bound states, the wave-number set $\{k_1, k_2\}$ of the incident states is not conserved and is scattered to the set $\{\epsilon_{\mathrm{d}} - \imath\Gamma, E - \epsilon_{\mathrm{d}} + \imath\Gamma\}$ including the imaginary part $\imath\Gamma$. We note that the terms of the two-body bound states decay with the distance of the two electrons but are stationary in time since the total energy eigenvalue is real; the imaginary parts of the complex wave numbers cancel out each other in the total energy eigenvalue. By the completeness of the plane-wave functions $\{\mathrm{e}^{\imath(k_1x_1+k_2x_2)} | k_1, k_2 \in \mathbb{R}\}$, the terms are expanded as

$$\mathrm{e}^{(\imath(\frac{E}{2}-\epsilon_{\mathrm{d}})-\Gamma)|x_1-x_2|+\imath E\frac{x_1+x_2}{2}} = \int dk_1' dk_2' \frac{1}{E - E' + \imath 0} c(k_1', k_2'; x_1, x_2)\mathrm{e}^{\imath(k_1'x_1+k_2'x_2)}, \tag{25}$$

where $E' = k_1' + k_2'$ and $c(k_1', k_2'; x_1, x_2)$ is the coefficient of the expansion. Hence we find that the terms of the two-body bound states describe the various scattering processes to the sets $\{k'_1, k'_2\}$ satisfying energy conservation $E = E'$. The coefficient $c(k'_1, k'_2; x_1, x_2)$ has the poles on the complex k'_1- and k'_2-planes which come from the resonant pole $k = \epsilon_{\rm d} - \imath\Gamma$ of the one-electron scattering eigenfunctions in Eqs. (13). Thus the two-body bound states appear as a consequence of one-body resonances[42].

The appearance of such many-body bound states is expected for general open QD systems with localized interactions. We have shown that two-body bound states appear in the Anderson model with spin degrees of freedom[34] and the double QD systems[35]. In Ref. 30, the N-electron scattering matrix for another QD system with interactions was explicitly constructed in a real-time representation, where two-electron scattering eigenstates are obtained in an integral form. We speculate that, by evaluating the integral form, two-body bound states similar to ours should appear.

C. *N*-electron cases

We can obtain the exact N-electron scattering eigenstates for arbitrary N. The scattering eigenstates for a few electrons can be constructed in a way similar to the two-electron cases. In the three-electron scattering eigenstates, for example, two electrons out of the three form the two-body bound states after the scattering at the QD[19]. The explicit form of the scattering eigenstates for a few electrons leads to a conjectural form of the N-electron scattering eigenstates. We have shown that they are indeed the eigenstates.

We present only the results in the first order of U_ℓ, which we need in the next section. The form of the N-electron scattering eigenstates is given by

$$\begin{aligned}|E\rangle = \Big(&\sum_{\{m_i\}}\int_{x_1<\cdots<x_N} d^N x\, g_{m_1\cdots m_N}(x_1,\ldots,x_N)c^\dagger_{m_1}(x_1)\cdots c^\dagger_{m_N}(x_N)\\ &+\sum_{\{n_i\}}\int_{x_1<\cdots<x_{N-1}} d^{N-1}x\, e_{n_1\cdots n_{N-1}}(x_1,\ldots,x_{N-1})c^\dagger_{n_1}(x_1)\cdots c^\dagger_{n_{N-1}}(x_{N-1})d^\dagger\Big)|0\rangle. \qquad (26)\end{aligned}$$

Here we impose the antisymmetric relations for the N-electron eigenfunctions as follows:

$$\begin{aligned}&g_{m_{Q_1}\cdots m_{Q_N}}(x_{Q_1},\ldots,x_{Q_N}) = {\rm sgn}(Q) g_{m_1\cdots m_N}(x_1,\ldots,x_N),\\ &e_{n_{R_1}\cdots n_{R_{N-1}}}(x_{R_1},\ldots,x_{R_{N-1}}) = {\rm sgn}(R) e_{n_1\cdots n_{N-1}}(x_1,\ldots,x_{N-1}), \qquad (27)\end{aligned}$$

where $Q = (Q_1,\ldots,Q_N)$ is a permutation of $(1,2,\ldots,N)$ and $R = (R_1,\ldots,R_{N-1})$ is that of $(1,2,\ldots,N-1)$. We consider the situation in which the electron with wave number k_i, $(i =$

$1, \ldots, N$) comes in through the lead ℓ_i to the QD. The N-electron scattering eigenfunctions are constructed in the first order of U_ℓ as

$$\begin{aligned}
&g^{(\ell_1 \cdots \ell_N)}_{m_1 \cdots m_N, k_1 \cdots k_N}(x_1, \ldots, x_N) \\
&= \sum_P \mathrm{sgn}(P) \prod_{i=1}^{N} g^{(\ell_{P_i})}_{m_i, k_{P_i}}(x_i) \\
&\quad + \frac{1}{2} \sum_{P,Q} \mathrm{sgn}(PQ) \prod_{i=1}^{N-2} g^{(\ell_{P_i})}_{m_{Q_i}, k_{P_i}}(x_{Q_i}) \theta(x_{Q_{N-2}}, \ldots, x_{Q_1}) \\
&\quad \times t_{m_{Q_{N-1}}} U_{m_{Q_N}} Z^{(\ell_{P_{N-1}} \ell_{P_N})}_{m_{Q_N}, k_{P_{N-1}} k_{P_N}}(x_{Q_{N-1} Q_N}) \mathrm{e}^{\imath (k_{P_{N-1}} + k_{P_N}) x_{Q_N}} \theta(x_{Q_N Q_{N-1}}) \theta(x_{Q_{N-1}}) \\
&\quad + O(U^2),
\end{aligned} \tag{28}$$

where P and Q are permutations of $(1, 2, \ldots, N)$, and

$$\begin{aligned}
&e^{(\ell_1 \cdots \ell_N)}_{n_1 \cdots n_{N-1}, k_1 \cdots k_N}(x_1, \ldots, x_{N-1}) \\
&= \sum_P \mathrm{sgn}(P) \prod_{i=1}^{N-1} g^{(\ell_{P_i})}_{n_i, k_{P_i}}(x_i) e^{(\ell_{P_N})}_{k_{P_N}} \\
&\quad + \frac{1}{2} \sum_{P,Q} \mathrm{sgn}(PQ) \prod_{i=1}^{N-3} g^{(\ell_{P_i})}_{n_{Q_i}, k_{P_i}}(x_{Q_i}) e^{(\ell_{P_{N-2}})}_{k_{P_{N-2}}} \theta(x_{Q_{N-3}}, \ldots, x_{Q_1}) \\
&\quad \times t_{n_{Q_{N-2}}} U_{n_{Q_{N-1}}} Z^{(\ell_{P_{N-1}} \ell_{P_N})}_{n_{Q_{N-1}}, k_{P_{N-1}} k_{P_N}}(x_{Q_{N-2} Q_{N-1}}) \mathrm{e}^{\imath (k_{P_{N-1}} + k_{P_N}) x_{Q_{N-1}}} \theta(x_{Q_{N-1} Q_{N-2}}) \theta(x_{Q_{N-2}}) \\
&\quad - \frac{1}{2} \sum_{P,Q} \mathrm{sgn}(PQ) \prod_{i=1}^{N-2} g^{(\ell_{P_i})}_{n_{Q_i}, k_{P_i}}(x_{Q_i}) \theta(x_{Q_{N-2}}, \ldots, x_{Q_1}) \\
&\quad \times U_{n_{Q_{N-1}}} Z^{(\ell_{P_{N-1}} \ell_{P_N})}_{n_{Q_{N-1}}, k_{P_{N-1}} k_{P_N}}(-x_{Q_{N-1}}) \mathrm{e}^{\imath (k_{P_{N-1}} + k_{P_N}) x_{Q_{N-1}}} \theta(x_{Q_{N-1}}) \\
&\quad + O(U^2),
\end{aligned} \tag{29}$$

where P is a permutation of $(1, 2, \ldots, N)$ and Q is that of $(1, 2, \ldots, N-1)$. Here we have used the notation

$$\theta(x_m, \ldots, x_2, x_1) = \theta(x_{m,m-1}) \cdots \theta(x_{32}) \theta(x_{21}). \tag{30}$$

The third term in Eq. (29) corresponds to the configuration in which one of the two electrons that form the two-body bound states is on the QD. On the other hand, the second term in Eq. (29) corresponds to the configuration in which both of the two electrons that form the two-body bound states are in the leads, which has not appeared in the two-electron scattering eigenfunction $e^{(\ell_1 \ell_2)}_{l, k_1 k_2}(x)$ in Eqs. (22) only in $g^{(\ell_1 \ell_2)}_{l, k_1 k_2}(x_1, x_2)$ in Eqs. (22). In what follows, we denote the eigenstate obtained by inserting the eigenfunctions in Eqs. (28) and (29) into Eq. (26) by $|k;\ell\rangle = |k_1,\dots,k_N;\ell_1,\dots,\ell_N\rangle$.

IV. ELECTRIC CURRENT UNDER BIAS VOLTAGES

A. N-electron current

By following the three steps of the extension of the Landauer formula given in Sec. II B, we next calculate the average electric current for the system under finite bias voltages[19,20]. First, we calculate the N-electron current, that is, the quantum-mechanical expectation value of the electric-current operator I with the N-electron scattering eigenstates $|k;\ell\rangle$. We assume $k_i \neq k_j$ if $\ell_i = \ell_j$ and restrict our calculation to the first order of U_ℓ. We need to calculate the following overlap integral:

$$\langle k;\ell|I|k;\ell\rangle = 2\mathrm{Im}\Big(\int_{x_1<\cdots<x_{N-1}} d^{N-1}x \sum_{\ell,\{n_i\}} (-1)^{\ell} \frac{|t_{\bar\ell}|^2}{t^2} t_\ell \\ \times g^*_{n_1\dots n_{N-1}\ell}(x_1,\dots,x_{N-1},0)\, e_{n_1\dots n_{N-1}}(x_1,\dots,x_{N-1})\Big), \tag{31}$$

where $\bar\ell = 3-\ell$. By inserting the N-electron eigenfunctions in Eqs. (28) and (29) into Eq. (31), we obtain

$$\begin{aligned}
&\langle k;\ell|I|k;\ell\rangle \\
&= \frac{|t_1t_2|^2}{\pi t^2}\Big(\frac{L}{2\pi}\Big)^{N-1} \sum_i (-1)^{\ell_i} \mathrm{Im}(G_{k_i}) \\
&\quad - \Big(\frac{L}{2\pi}\Big)^{N-2} \sum_{i\neq j} (-1)^{\ell_i} \sum_m U_m \mathrm{Im}\Big(\frac{2t_1t_2}{t^2} e^{(\bar\ell_i)}_{k_i} g^{(\ell_j)*}_{m,k_j}(0+) Z^{(\ell_i\ell_j)}_{\ell,k_ik_j}(0)\Big) \\
&\quad - \frac{2|t_1t_2|^2}{\pi t^2}\Big(\frac{L}{2\pi}\Big)^{N-3} \sum_{i\neq j\neq l(\neq i)} (-1)^{\ell_i} \mathrm{Im}(G_{k_i}) \sum_m U_m \mathrm{Re}\big(G_{k_j} g^{(\ell_l)*}_{m,k_l}(0+) e^{(\ell_j)*}_{k_j} Z^{(\ell_j\ell_l)}_{m,k_jk_l}(0)\big) \\
&\quad + O(U^2).
\end{aligned} \tag{32}$$

Here L is the system length coming from the regularized square norm $\langle k;\ell|k;\ell\rangle = L/(2\pi)$ of the one-electron scattering eigenstates. In order to express the results, we have used the notation

$$G_k = \frac{1}{k-\epsilon_{\mathrm{d}}+\imath\Gamma}, \tag{33}$$

which is the one-electron Green's function on the QD. We notice that the choice of the parameter α in Eqs. (2) simplifies the calculation. On the other hand, the square norm of the N-electron eigenstates is calculated as

$$\begin{aligned}
&\langle k;\ell|k;\ell\rangle \\
&= \sum_{\{m_i\}} \int_{x_1<\cdots<x_N} d^N x\, |g_{m_1\cdots m_N}(x_1,\ldots,x_N)|^2 + \sum_{\{n_i\}} \int_{x_1<\cdots<x_{N-1}} d^{N-1}x\, |e_{n_1\cdots n_{N-1}}(x_1,\ldots,x_{N-1})|^2 \\
&= \Big(\frac{L}{2\pi}\Big)^N - 2\Big(\frac{L}{2\pi}\Big)^{N-2} \sum_{i\neq j} \sum_{m=1,2} U_m \mathrm{Re}\big(G_{k_i} g^{(\ell_j)*}_{m,k_j}(0+) e^{(\ell_i)*}_{k_i} Z^{(\ell_i\ell_j)}_{m,k_ik_j}(0)\big) + O(U^2). \qquad (34)
\end{aligned}$$

It should be noted that the term in the $(N-1)$th order in L does not appear above. Combining Eqs. (32) and (34), we obtain the N-electron current as

$$\begin{aligned}
&\frac{\langle k;\ell|I|k;\ell\rangle}{\langle k;\ell|k;\ell\rangle} \\
&= \frac{|t_1t_2|^2}{\pi t^2}\frac{2\pi}{L}\sum_{i=1}^{N}(-1)^{\ell_i}\mathrm{Im}(G_{k_i}) \\
&\quad - \frac{4\pi^2}{L^2}\sum_{i\neq j}(-1)^{\ell_i}\sum_{m=1,2} U_m \mathrm{Im}\Big(\frac{2t_1t_2}{t^2} e^{(\bar{\ell}_i)}_{k_i} g^{(\ell_j)*}_{m,k_j}(0+) Z^{(\ell_i\ell_j)}_{m,k_ik_j}(0)\Big) \\
&\quad + \frac{2|t_1t_2|^2}{\pi t^2}\frac{8\pi^3}{L^3}\sum_{i\neq j}\mathrm{Im}\big((-1)^{\ell_i}G_{k_i} + (-1)^{\ell_j}G_{k_j}\big)\sum_{m=1,2} U_m \mathrm{Re}\big(G_{k_i} g^{(\ell_j)*}_{m,k_j}(0+) e^{(\ell_i)*}_{k_i} Z^{(\ell_i\ell_j)}_{m,k_ik_j}(0)\big) \\
&\quad + O(U^2). \qquad (35)
\end{aligned}$$

B. Average electric current

Next, we take the reservoir limit of the N-electron current in Eq. (35) to obtain the average electric current. We assume that the infinite lead substitutes for a large electron reservoir characterized by the Fermi distribution function $f_{\mu,\beta}(k) = 1/(1+\mathrm{e}^{\beta(k-\mu)})$ with a chemical potential μ and an inverse temperature β. We also assume that electrons are completely equilibrated in each electron reservoir before being re-emitted towards the QD, which is the main assumption of the extension of the Landauer formula.

In the N-electron current in Eq. (35), the N-dependence appears only in the upper bounds of the sums on the wave numbers together with the factor $2\pi/L$, which means that we can take the reservoir limit $N_\ell, L \to \infty$ described in Sec. II B. It should be noted that the first term in Eq. (35) contains a single sum on i with the factor $2\pi/L$ and the second term contains a double sum on i and j with $(2\pi/L)^2$ while the third term is a double sum on i and j with $(2\pi/L)^3$ due to the square norm $\langle k;\ell|k;\ell\rangle$ appearing in the denominator. Therefore the third term in Eq. (35) vanishes in the reservoir limit $N_\ell, L \to \infty$.

In order to investigate the average electric current, we set $\ell_1 = \cdots = \ell_{N_1} = 1$ and $\ell_{N_1+1} = \cdots = \ell_N = 2$ in Eq. (35) and relabel $|k;\ell\rangle$ by $|k,h\rangle$ with $h_i = k_{N_1+i}$, $(1 \le i \le N_2)$. The N-electron current is rewritten as follows:

$$\frac{\langle k,h|I|k,h\rangle}{\langle k,h|k,h\rangle} = J_0 + J_1 + J_2 + O(U^2), \tag{36a}$$

$$J_0 = -\frac{2\Gamma_1\Gamma_2}{\pi\Gamma}\frac{2\pi}{L}\Big[\sum_{i=1}^{N_1}\mathrm{Im}\big(G_{k_i}\big) - \sum_{i=1}^{N_2}\mathrm{Im}\big(G_{h_i}\big)\Big], \tag{36b}$$

$$J_1 = -\frac{\Gamma_1\Gamma_2}{\pi^2\Gamma}\frac{4\pi^2}{L^2}\Big[U_1\sum_{1\le i\ne j\le N_1}\xi^{(11)}_{k_ik_j} + \sum_{\substack{1\le i\le N_1\\ 1\le j\le N_2}}\big(U_1\xi^{(12)}_{k_ih_j} + U_2\xi^{(21)}_{h_jk_i}\big) + U_2\sum_{1\le i\ne j\le N_2}\xi^{(22)}_{h_ih_j}\Big], \tag{36c}$$

where we use

$$\xi^{(lm)}_{kh} = \mathrm{Im}\Big[G_h\Big((-1)^l\delta_{lm}G_k - (-1)^mG_h + 2\imath\big((-1)^l\Gamma_mG^*_hG_k - (-1)^m\Gamma_lG^*_kG_h\big)\Big)\Big] \tag{37}$$

and $\Gamma_l = |t_l|^2/2$. We omit the explicit form of J_2 in Eq. (36a) since it does not contribute to the average electric current in the reservoir limit $N_\ell, L \to \infty$. Thus the parts of the N-electron current that contribute to the average electric current are detemined by the two-electron scattering eigenstates.

In the reservoir limit $N_\ell, L \to \infty$, we replace the sums on k_i in Eq. (36a) by the integral on k with $f_{\mu,\beta}(k)$ as

$$\frac{2\pi}{L}\sum_{i=1}^{N_\ell}J(k_i) \to \int_{-\Lambda}^{\infty}dk\, f_{\mu_\ell,\beta_\ell}(k)J(k), \tag{38}$$

where we need to introduce the low-energy cutoff $-\Lambda$ since the local dispersion relation of the lead is bottomless. At zero temperature ($\beta_\ell = \infty$), the average electric current is given by

$$\langle I\rangle = -\frac{2\Gamma_1\Gamma_2}{\pi\Gamma}\int_{\mu_2}^{\mu_1}dk\,\mathrm{Im}\big(G_k\big) - \frac{\Gamma_1\Gamma_2}{\pi\Gamma}\sum_{\ell=1,2}U_\ell\int_{-\Lambda}^{\mu_\ell}dk\Big(\int_{-\Lambda}^{\mu_\ell}dh\,\xi^{(\ell\ell)}_{kh} + \int_{-\Lambda}^{\mu_{\bar\ell}}dh\,\xi^{(\ell\bar\ell)}_{kh}\Big) + O(U^2). \tag{39}$$

We notice that the first term in Eq. (39) reproduces the original Landauer formula in the noninteracting cases. The double summations in Eq. (36c) give double integrals in the second term in Eq. (39), which give a contribution of the Coulomb interactions. Through the integral formulas

$$\begin{aligned}\int_{-\Lambda}^{\mu_\ell} dk\, G_k &= \frac{1}{2}\log\Big(\frac{\epsilon_\ell^2+1}{\epsilon_\Lambda^2+1}\Big) + \imath(\arctan(\epsilon_\ell) - \arctan(\epsilon_\Lambda)),\\ \int_{-\Lambda}^{\mu_\ell} dk\, G_k^2 &= \frac{1}{\Gamma}\Big(\frac{1}{\epsilon_\ell - \imath} - \frac{1}{\epsilon_\Lambda - \imath}\Big), \qquad (40a)\\ \int_{-\Lambda}^{\mu_\ell} dk\, G_k^* G_k &= -\frac{1}{\Gamma}(\arctan(\epsilon_\ell) - \arctan(\epsilon_\Lambda)), \qquad (40b)\end{aligned}$$

with $\epsilon_\ell = (\epsilon_{\mathrm{d}} - \mu_\ell)/\Gamma$ and $\epsilon_\Lambda = (\epsilon_{\mathrm{d}} + \Lambda)/\Gamma$, we obtain the average electric current

$$\begin{aligned}\langle I\rangle = &-\frac{2\Gamma_1\Gamma_2}{\pi\Gamma} j_-\\ &+ \frac{\Gamma_1\Gamma_2}{\pi^2\Gamma^2}\sum_{\ell=1,2} U_\ell\Big[\big(\Gamma_{\bar\ell} j_- - \Gamma_\ell j_1\big)\log\Big(\frac{\epsilon_\ell^2+1}{\epsilon_\Lambda^2+1}\Big) + \big(\Gamma(\epsilon_\ell - \epsilon_\Lambda) - \Gamma_\ell\big(2\arctan(\epsilon_\ell) - j_\Lambda\big)\big) j_2\Big]\\ &+ O(U^2), \qquad (41)\end{aligned}$$

where we use the notation

$$\begin{aligned}&j_- = \arctan(\epsilon_1) - \arctan(\epsilon_2), \quad j_\Lambda = 2\arctan(\epsilon_\Lambda),\\ &j_s = \frac{\epsilon_1^{2-s}}{\epsilon_1^2+1} - \frac{\epsilon_2^{2-s}}{\epsilon_2^2+1}, \quad (s = 1, 2). \qquad (42)\end{aligned}$$

We find that the average electric current $\langle I\rangle$ contains linear and logarithmic divergences in the limit $\Lambda \to \infty$, which is similar to the symmetric case $U_1 = U_2$[19,20,24].

C. Universal electric current

We employ a renormalization-group technique to deal with the divergences in the average electric current in Eq. (41). The divergences are due to the bottomless dispersion relation. By the renormalization-group analysis, we zoom into the Fermi energy and thereby discard all details that arise from the specifics of the dispersion relation. As a result, we obtain a universal form of the average electric current.

We devise a Callan-Symanzik equation[24,26] so that the average electric current may satisfy it. Let us introduce a parameter $D = \Gamma\sqrt{\epsilon_\Lambda^2 + 1}$. We can indeed see that, for $D \gg \Gamma, |\epsilon_{\mathrm{d}}|$, the average electric current $\langle I\rangle$ in Eq. (41) satisfies

$$\Big(D\frac{\partial}{\partial D} + \sum_{\ell=1,2}\beta_{\Gamma_\ell}\frac{\partial}{\partial\Gamma_\ell} + \beta_{\epsilon_{\mathrm{d}}}\frac{\partial}{\partial\epsilon_{\mathrm{d}}}\Big)\langle I\rangle = 0, \qquad (43)$$

where the beta functions β_{Γ_ℓ} and $\beta_{\epsilon_{\rm d}}$ are given in the first order of U_ℓ as

$$\beta_{\Gamma_\ell} = -\frac{U_\ell}{\pi}\Gamma_\ell + O(U^2), \quad \beta_{\epsilon_{\rm d}} = -\frac{\bar{U}}{\pi}D + O(U^2) \tag{44}$$

with the average interaction $\bar{U} = (U_1 + U_2)/2$. The Callan-Symanzik equation of the form (43) is an extension of the previous ones [19,20,24] for the case of the symmetric couplings.

The general solution of the Callan-Symanzik equation determines a scaling form of the average electric current as

$$\langle I\rangle = J\Big(D^{\frac{U_1}{\pi}}\Gamma_1, D^{\frac{U_2}{\pi}}\Gamma_2, \epsilon_{\rm d} + \frac{\bar{U}}{\pi}D\Big), \tag{45}$$

where $J(\cdot,\cdot,\cdot)$ is an arbitrary three-variable function. Hence, if we change the parameters Γ_ℓ and $\epsilon_{\rm d}$ as functions in D as

$$\Gamma_\ell(D) = T_\ell\Big(\frac{T_{\rm K}}{D}\Big)^{\frac{U_\ell}{\pi}}, \quad \epsilon_{\rm d}(D) = E_{\rm d} - \frac{\bar{U}}{\pi}D \tag{46}$$

with the constants T_1, T_2, ($T_{\rm K} = T_1 + T_2$) and $E_{\rm d}$, the average electric current $\langle I\rangle$ does not depend on D. The parameters $\Gamma_\ell(D)$ and $\epsilon_{\rm d}(D)$ are referred to as renormalized parameters while the original parameters are called "bare" parameters, which we denote by $\Gamma_{\ell,0}$, $\epsilon_{{\rm d},0}$ and D_0. Here we fix the renormalized constants T_ℓ and $E_{\rm d}$ by the bare parameters as

$$T_\ell = \Gamma_{\ell,0}\Big(\frac{D_0}{T_{\rm K}}\Big)^{\frac{U_\ell}{\pi}}, \quad E_{\rm d} = \epsilon_{\rm d} + \frac{\bar{U}}{\pi}D_0 \tag{47}$$

and express all physical quantities in terms of the renormalized ones. We shall see below that the sum $T_{\rm K} = T_1 + T_2$ plays a role of a scaling parameter similar to the Kondo temperature.

By inserting the renormalized parameters in Eqs. (46) into the average electric current $\langle I\rangle$ in Eq. (41) and rearranging it with respect to the interaction parameter U_ℓ, we obtain the universal electric current

$$\begin{aligned}\langle I\rangle = &-\frac{2T_1T_2}{\pi T_{\rm K}}\tilde{j}_- \\ &+ \frac{T_1T_2}{\pi^2T_{\rm K}^2}\sum_\ell U_\ell\Big[\big(T_{\bar{\ell}}\tilde{j}_- - T_\ell\tilde{j}_1\big)\log(\tilde{\epsilon}_\ell^2 + 1) + \big(T_{\rm K}\tilde{\epsilon}_\ell - T_\ell\big(2\arctan(\tilde{\epsilon}_\ell) - \pi\big)\big)\tilde{j}_2\Big] \\ &+ O(U^2),\end{aligned} \tag{48}$$

where $\tilde{j}_-$ and $\tilde{j}_s$ are j_- and j_s with $\tilde{\epsilon}_\ell = (E_{\rm d} - \mu_\ell)/T_{\rm K}$ in place of ϵ_ℓ, respectively. Thus the average electric current $\langle I\rangle$, which was originally described by the bare parameters $\Gamma_{\ell,0}$, $\epsilon_{{\rm d},0}$,

D_0 and U_ℓ, is now characterized by the parameters T_ℓ, E_d and U_ℓ. As a result, the linear and the logarithmic divergences of the average electric current are absorbed into the parameters T_ℓ and E_d.

Let us consider the current-voltage (I-V) characteristics of the universal electric current. We put $E_\mathrm{d} = 0$ and consider the cases $\mu_1 = -\mu_2 = V/2$ with the bias voltage V. Then we have

$$\begin{aligned}\frac{T_\mathrm{K}}{4T_1T_2}\langle I\rangle = {} & \frac{1}{\pi}\arctan\Big(\frac{V}{2T_\mathrm{K}}\Big) \\ & - \frac{1}{2\pi^2}\Big[(\bar{U}-\delta)\arctan\Big(\frac{V}{2T_\mathrm{K}}\Big) - (\bar{U}+\delta)\frac{V/(2T_\mathrm{K})}{V^2/(2T_\mathrm{K})^2+1}\Big]\log\Big(\Big(\frac{V}{2T_\mathrm{K}}\Big)^2+1\Big) \\ & + O(U^2), \end{aligned} \tag{49}$$

where δ is the asymmetry parameter defined by

$$\delta = \frac{(U_1-U_2)(T_1-T_2)}{2T_\mathrm{K}}. \tag{50}$$

We note that the parameters T_1 and T_2 depend on U_1 and U_2 through Eqs. (47).

We find from Eq. (49) that the bias voltage V is scaled by the parameter T_K. In the case of symmetric interactions $U_1 = U_2$, we have $\delta = 0$. Hence, after taking appropriate scaling factors for the electric current $\langle I\rangle$ and the bias voltage V, the I-V curve is independent of the parameters T_1 and T_2. In the asymmetric cases with $\Gamma_{1,0} \neq \Gamma_{2,0}$ and $U_1 \neq U_2$, on the other hand, the parameters T_1 and T_2 play a nontrivial role since, even if we rescale the electric current, it still depends on T_1 and T_2 through the asymmetry parameter δ.

We deal with the parameters T_1 and T_2 in the first order of U_ℓ. By solving the equation for T_K, which is obtained by the first equation in Eqs. (47), the parameter T_ℓ is expanded in the first order of U_ℓ as

$$T_\ell = \Gamma_{\ell,0}\Big(1+\frac{U_\ell}{\pi}\log\Big(\frac{D_0}{\Gamma_0}\Big)\Big) + O(U^2). \tag{51}$$

We remark that, for the consistency with the expansion, the ratio D_0/Γ_0 should be restricted to the region $D_0/\Gamma_0 \ll \mathrm{e}^{\pi/U_\ell}$. Then the asymmetry parameter δ in Eq. (50) is expanded as

$$\delta = \frac{(U_1-U_2)(\Gamma_{1,0}-\Gamma_{2,0})}{2\Gamma_0} + O(U^2). \tag{52}$$

By a physical intuition, we expect $\delta \geq 0$ since the case $U_1 > U_2$ should correspond to the case $\Gamma_{1,0} > \Gamma_{2,0}$. By expressing the parameters as $\Gamma_{1/2,0} = \Gamma_0(1 \pm \gamma)/2$ with $0 \leq \gamma < 1$

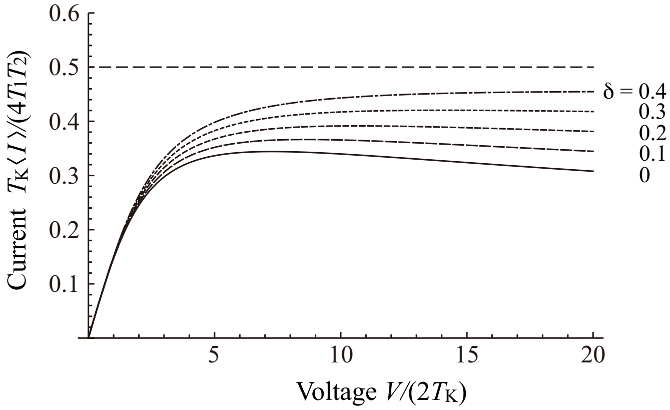

FIG. 3: *I*-*V* characteristics of the rescaled universal electric current for $\bar{U} = 0.5$ with $\delta = 0, 0.1, 0.2, 0.3, 0.4$.

and $U_{1/2} = \bar{U}(1 \pm \gamma')$ with $0 \leq \gamma' \leq 1$ in the cases with $\Gamma_{1,0} \geq \Gamma_{2,0} > 0$ and $U_1 \geq U_2$, we have $\delta = \bar{U}\gamma\gamma' + O(U^2)$. Hence the asymmetry parameter δ takes a value in the range $0 \leq \delta < \bar{U} + O(U^2)$. The *I*-*V* curve of the universal electric current for $\bar{U} = 0.5$ and $0 \leq \delta < 0.5$ is depicted in Fig. 3.

We observe the suppression of the electric current for large bias voltages $V \gg T_\mathrm{K}$, that is, *negative differential conductance*. This is because the formation of the two-body bound states promotes the reflection of electrons at the QD, as is illustrated in Fig. 2, and the logarithmic term in Eq. (49) decreases the electric current. In the first order of U_ℓ, the negative differential conductance shows the power-law behavior $\langle I\rangle \propto (V/T_\mathrm{K})^{-(\bar{U}-\delta)/\pi}$ where the asymmetry parameter δ appears. This means that the suppressed electric current is restored by the asymmetry of the system parameters. In the case $\Gamma_{1,0} = \Gamma_{2,0}$, we have $\delta = 0$ in the first order of U_ℓ and the universal electric current in Eq. (49) depends only on the average interaction $\bar{U}$. This is consistent with the Callan-Symanzik equation: by changing the variables and setting $\Gamma_1 = \Gamma_2 = \Gamma/2$, the Callan-Symanzik equation (43) is reduced to

$$\Big(D\frac{\partial}{\partial D} + \beta_\Gamma\frac{\partial}{\partial\Gamma} + \beta_{\epsilon_\mathrm{d}}\frac{\partial}{\partial\epsilon_\mathrm{d}}\Big)\langle I\rangle = 0 \tag{53}$$

with the beta function $\beta_\Gamma = -\bar{U}\Gamma/\pi + O(U^2)$. The general solution is given in the form $\langle I\rangle = J(D^{\frac{\bar{U}}{\pi}}\Gamma, \epsilon_\mathrm{d} + \bar{U}D/\pi)$ with an arbitrary two-variable function $J(\cdot,\cdot)$. Then the negative differential conductance appears for $\bar{U} > 0$, which is essentially the same as the previous results in the case of symmetric interactions $U_1 = U_2$[20,24,25].

Let us compare the present results with the renormalization-group (RG) results in Refs. 31

and 32; the RG flow equations for the level width Γ were obtained in the second order of U_ℓ in Ref. 32. Although general local dispersion relations of the leads were adopted in Refs. 31 and 32, the details of the frequency dependence of the density of states of the leads did not play any role in their analysis. Indeed, the linear divergence in our average electric current $\langle I\rangle$ due to the linearized dispersion relations is removed by the RG technique with the Callan-Symanzik equation as we have described above. Their definition of the parameters T_1 and T_2, which was approximately derived from the RG flow equations for the level width Γ, is equivalent to ours in Eq. (47) in the first order of U_ℓ.

We can confirm that the universal electric current in Eq. (49) is consistent with that of the RG results[31,32] in the first order of U_ℓ. By using the renormalized band width $\Gamma_\ell(D)$ in Eq. (46), we have

$$\begin{aligned}
&\frac{\Gamma_1(D)\Gamma_2(D)}{\Gamma(D)}\arctan\left(\frac{V}{2\Gamma(D)}\right)\\
&= \frac{T_1T_2}{T_{\mathrm{K}}}\Bigg[\arctan\left(\frac{V}{2T_{\mathrm{K}}}\right)\\
&\quad -\frac{1}{2\pi}\left[(\bar{U}-\delta)\arctan\left(\frac{V}{2T_{\mathrm{K}}}\right)-(\bar{U}+\delta)\frac{V/(2T_{\mathrm{K}})}{V^2/(2T_{\mathrm{K}})^2+1}\right]\log\left(\frac{D^2}{T_{\mathrm{K}}^2}\right)\Bigg]+O(U^2). \qquad (54)
\end{aligned}$$

Then, by putting $\tilde{\Gamma}_\ell = \Gamma_\ell(|V/2+\imath T_{\mathrm{K}}|)$ and $\tilde{\Gamma} = \tilde{\Gamma}_1+\tilde{\Gamma}_2$, the universal electric current in Eq. (49) is expressed by

$$\langle I\rangle = \frac{4\tilde{\Gamma}_1\tilde{\Gamma}_2}{\pi\tilde{\Gamma}}\arctan\left(\frac{V}{2\tilde{\Gamma}}\right)+O(U^2), \qquad (55)$$

which is in the same form as the noninteracting cases. The expression in Eq. (55) agrees with that obtained in the RG results (see Appendix A).

We remark that, although the expression of the universal electric current in Refs. 31 and 32 agrees with ours in Eq. (55), their treatment of the renormalized parameters T_1 and T_2 included in the universal electric current is different from ours; they used the higher-order terms of U_ℓ in the defining relations of T_1 and T_2 in Eq. (47) while we have treated them in the first order of U_ℓ as is given Eq. (51). As a result, even in the case $\Gamma_{1,0} = \Gamma_{2,0}$ of symmetric lead-dot couplings, they observed the restoration of the suppressed electric current. We have shown that, for the asymmetry parameter δ treated in the first order of U_ℓ, the restoration due to the asymmetric interactions does not occur at $\Gamma_{1,0} = \Gamma_{2,0}$. In other words, in this case, there should be no restoration of the suppressed electric current for small U_ℓ, which seems to differ from the results of Refs. 31 and 32.

V. CONCLUDING REMARKS

We have studied the average electric current for the open QD systems described by the two-lead IRLM in the asymmetric settings. By using the extension of the Landauer formula with the many-electron scattering eigenstates, we have calculated the average electric current for the systems under finite bias voltages. The calculation is in the first order of the interaction parameters, but otherwise we have not employed any approximations. The calculation itself has been considerably simplified compared to the previous one[19,20] treating the symmetric cases with the even-odd transformation.

Through the renormalization-group technique with the Callan-Symanzik equation, we have obtained the universal electric current characterized by the scaling parameter T_{K} and the asymmetry parameter δ. The Coulomb interactions around the QD give rise to the negative differential conductance through the formation of the two-body bound states, which is a new point of view clarified in our analysis. Through the investigation of the asymmetry parameter δ, we have confirmed in the first order of U_1 and U_2 that the suppressed electric current is restored in the asymmetric cases satisfying both $\Gamma_{1,0} \neq \Gamma_{2,0}$ and $U_1 \neq U_2$.

The analytic form of the universal electric current has enabled us to compare it with those of other approaches correctly. Our universal electric current has the same functional form as that obtained with the RG approach[31,32]; it also reproduces previous results[20,23–25,27] in the symmetric cases. However, for $U_1 \neq U_2$ and $\Gamma_{1,0} = \Gamma_{2,0}$, our results indicate that there is no restoration of the suppressed electric current to first order in U_1 and U_2, while Refs. 31 and 32 indicate that there is. This restoration may result from higher-order terms in U_1 and U_2. To verify its validity analytically, we need a consistent treatment of these higher-order terms, which can be done with our extension of the Landauer formula.

The key element for the practical calculations in the extension of the Landauer formula is the explicit form of many-electron scattering eigenstates. The present calculation in the first order in the interaction parameters can be extended to higher orders by using the exact N-electron scattering eigenstates that we have already obtained. We expect that such calculation should be applied to other physical quantities of the open QD systems such as the dot occupancy.

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Appendix A: Results of the RG flow equation for Γ

In our settings, the universal electric current obtained in Refs. 31 and 32 is expressed as

$$\langle I\rangle_{\mathrm{RG}} = \frac{2\hat{\Gamma}_1\hat{\Gamma}_2}{\pi\hat{\Gamma}}\Big[\arctan\Big(\frac{\mu_1-\epsilon_{\mathrm{d}}}{\hat{\Gamma}}\Big)-\arctan\Big(\frac{\mu_2-\epsilon_{\mathrm{d}}}{\hat{\Gamma}}\Big)\Big], \tag{A1}$$

where $\hat{\Gamma}_\ell$ is the solution of the RG flow equations for the level width of the QD and $\hat{\Gamma} = \hat{\Gamma}_1 + \hat{\Gamma}_2$. It was approximately determined by the self-consistent equation

$$\hat{\Gamma}_\ell \simeq \Gamma_{\ell,0}\Big(\frac{D_0}{|\hat{\Gamma} - \imath(\mu_\ell - \epsilon_{\mathrm{d}})|}\Big)^{g_\ell} \tag{A2}$$

with $g_\ell = U_\ell/\pi + O(U^2)$. In the first order of U_ℓ, the approximate solution is given by

$$\begin{aligned}\hat{\Gamma}_\ell &\simeq T_\ell\Big(\frac{T_{\mathrm{K}}}{|\hat{\Gamma} - \imath(\mu_\ell - \epsilon_{\mathrm{d}})|}\Big)^{\frac{U_\ell}{\pi}} + O(U^2)\\ &= T_\ell\Big(\frac{T_{\mathrm{K}}}{|T_{\mathrm{K}} - \imath(\mu_\ell - \epsilon_{\mathrm{d}})|}\Big)^{\frac{U_\ell}{\pi}} + O(U^2)\\ &= \Gamma_\ell(|(\mu_\ell - \epsilon_{\mathrm{d}}) + \imath T_{\mathrm{K}}|) + O(U^2),\end{aligned} \tag{A3}$$

where $\Gamma_\ell(D)$ is the renormalized level width defined in Eq. (46). By inserting this into Eq. (A1) and setting $\mu_{1/2} = \pm V/2$ and $\epsilon_{\mathrm{d}} = 0$, the expression in Eq. (A1) agrees with Eq. (55).

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